PATENT COOPERATION TREATY

Translation

PCT

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference UKZ-P004WO			FOR FURTHER A	CTION	See Form PCT/IPEA/416		
International application No.			International filing da	te (day/month/year)	Priority date (day/month/year)		
PCT/DE2004/000835			22.04.200	4	07.05.2003		
International Patent Classification (IPC) or national classification and IPC							
Applicant UNIVERSITÄT KONSTANZ							
	 This report is the international preliminary examination report, established by this International Preliminary Examining Authority under Article 35 and transmitted to the applicant according to Article 36. 						
2. Th	is REPORT consists	of a total of	5	sheets, including	this cover sheet.		
3. Th	is report is also accor	mpanied by Al	NNEXES, comprising:				
a.	(sent to the	applicant and	to the International Bu	reau) a total of	sheets, as follows:		
	sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions).						
	sheets which supersede earlier sheets, but which this Authority considers contain an amendment that goes beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. I and the Supplemental Box.						
ь.		International i	Bureau only) a total of	(indicate type and number	r of electronic carrier(s))		
					, containing a sequence listing and/or tables		
	related thereto, in computer readable form only, as indicated in the Supplemental Box Relating to Sequence Listing (see Section 802 of the Administrative Instructions).						
4. Th	is report contains ind	lications relati	ng to the following iter	ns:			
	Box No. I	Basis of the	report				
ł L	Box No. II	Priority					
	Box No. III	Non-establi	shment of opinion with	regard to novelty, inventi	ive step and industrial applicability		
L	Box No. IV	Lack of unit	ty of invention				
	Box No. V		atement under Article d explanations supporti	• •	ty, inventive step or industrial applicability;		
	Box No. VI	Certain doc	uments cited				
	Box No. VII	Certain defe	ects in the international	application			
	Box No. VIII	Certain obs	ervations on the interna	tional application			
Date of submission of the demand Date of completion of this report							
Name and mailing address of the IPEA/EP				Authorized officer			
Facsimile No.				Telephone No.			

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

PCT/DE2004/000835

Вох	No. I	Basis of the report	
1.		h regard to the language, this report is based on the international cated under this item.	application in the language in which it was filed, unless otherwise
		This report is based on translations from the original language which is the language of a translation furnished for the purpose international search (Rule 12.3 and 23.1(b)) publication of the international application (Rule 12.4) international preliminary examination (Rule 55.2 and/or	es of:
2.	recei		port is based on (replacement sheets which have been furnished to the referred to in this report as "originally filed" and are not annexed to an are not annexed to a soriginally filed/furnished
		pages*	received by this Authority on
		pages*	-
	\square		
		the claims:	
		nos. <u>1-9</u>	as originally filed/furnished
		nos.*	as amended (together with any statement) under Article 19
		nos.*	received by this Authority on
		nos.*	received by this Authority on
	\boxtimes	the drawings:	
		sheets 1/6-6/6	as originally filed/furnished
		sheets*	received by this Authority on
		sheets*	received by this Authority on
		a sequence listing and/or any related table(s) – see Supplemen	tal Box Relating to Seguence Listing
_	$\overline{\Box}$		an Don remains to Sequence Essuing.
3.	Ш	The amendments have resulted in the cancellation of:	
		the description, pages	
		the claims, nos.	
		the drawings, sheets/figs	
		the sequence listing (specify):	
		any table(s) related to sequence listing (specify):	
4.		This report has been established as if (some of) the amendmenthey have been considered to go beyond the disclosure as filed	ents annexed to this report and listed below had not been made, since L as indicated in the Supplemental Box (Rule 70.2(c)).
		the description, pages	
		the claims, nos.	
		the drawings, sheets/figs	
*	If ite	em 4 applies, some or all of those sheets may be marked "supers	

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International application No.
PCT/DE2004/000835

Вох		nt under Article 35(2) with regard to novelty, inventive step or industrial applicability; mations supporting such statement	
1.	Statement		
:	Novelty (N)	Claims 1, 2, 4, 9	YES NO
	Inventive step (IS)	Claims Claims 3, 5-8	YES NO
	Industrial applicability (IA)	Claims 1-9 Claims	
2.	Citations and explanations (Rule	70.7)	
	Reference	e is made to the following documents:	
		.99 62 136 A (MERCK PATENT GMBH) 28 June	
	D2: US-E	31-6 309 467 (PICHLER HERBERT ET AL)	
	30 C	October 2001 (2001-10-30)	
	PCT Articological percentage could mean percent, term "per		
		2 and 5 are also unclear because the acentrated" does not have a precise	
	requireme subject m	ent application does not meet the ents of PCT Article 33(1) because the matter of claims 1, 2, 4 and 9 lacks (PCT Article 33(2)).	

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

2.1 Document D1 discloses (column 3, lines 39-63):

method for texturing surfaces of silicon wafers, comprising the steps of dipping the silicon wafers into an etching solution consisting of water, concentrated hydrofluoric acid and concentrated nitric acid and setting the temperature of the etching solution, characterised in that the etching solution consists proportionally of 20% to 55% water, 10% to 40% concentrated hydrofluoric acid and 20% to 60% concentrated nitric acid and in that the temperature of the etching solution lies between 0 degrees Celsius and 15 degrees Celsius.

The subject matter of claim 1 thus lacks novelty.

2.2 Regarding claim 2, D1 also discloses (column 3, lines 56-58):

the etching solution consists proportionally of 30% to 40% water, 15% to 30% concentrated hydrofluoric acid and 30% to 50% concentrated nitric acid.

2.3 Regarding claim 4, D1 also discloses (column 3, lines 60-63):

the silicon wafers remain in the etching solution for 2 to 30 minutes.

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Box No. V	No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement			
2.4	Regarding claim 9, D1 also discloses (column 3,			
	lines 13-19):			
	the silicon wafers are multicrystalline.			
3	The present application does not meet the			
	requirements of PCT Article 33(1) because the			
	subject matter of claims 3 and 5-8 does not			
	involve an inventive step (PCT Article 33(3)).			
3.1	Regarding claims 3 and 5: a person skilled in the			
	art would determine the temperature of the etching			
	solution and the treatment time by experimental			
	tests. D2 discloses a treatment temperature of			
	between 8 degrees Celsius and 10 degrees Celsius			
	(column 4, lines 26-28). It would be obvious to a			
	person skilled in the art to combine the teachings			
	of documents D1 and D2. Since the term "percent"			
	in claim 5 is unclear, an inventive step is not			
	acknowledged.			
3.2	Regarding claims 6-8: a person skilled in the art			
	would decide on merit how to orient the silicon			
	wafers and whether the etching solution or the			
	wafers should be moved.			